NSN 5961-00-577-0429

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Inclosure Material:

Metal

Overall Length:

1.252 inches

Overall Height:

0.340 inches

Overall Width:

0.700 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector to emitter, sustained and 8.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

10.00 amperes source cutoff current

Power Rating Per Characteristic:

25.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Test Data Document:

82577-928446 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 pin and 1 case Shelf Life: N/a Unit Of Measure: --Demilitarization: No Fiig:

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